

# **isc** Silicon NPN Power Transistor

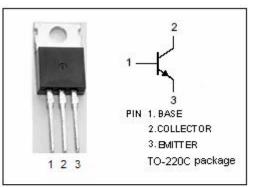
# 2SD861

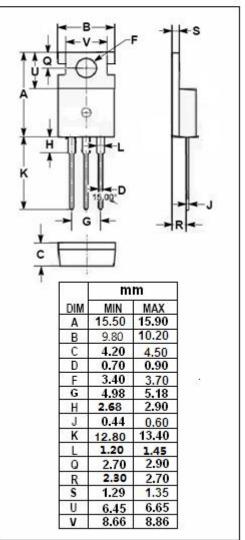
## DESCRIPTION

- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 250V(Min)
- High Power Dissipation-
  - : P<sub>C</sub>= 45W@ T<sub>C</sub>= 25°C
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

• Designed for audio frequency power amplifier applications.





## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER	VALUE	UNIT
Collector-Base Voltage	350	V
Collector-Emitter Voltage	250	V
Emitter-Base Voltage	5	V
Collector Current-Continuous	1.5	A
Collector Current-Peak	3.0	A
Collector Power Dissipation @ $T_c=25^{\circ}C$	45	W
Junction Temperature	150	°C
Storage Temperature Range	-55~150	°C
	Collector-Base Voltage   Collector-Emitter Voltage   Emitter-Base Voltage   Collector Current-Continuous   Collector Current-Peak   Collector Power Dissipation @ Tc=25℃   Junction Temperature	Collector-Base Voltage350Collector-Emitter Voltage250Emitter-Base Voltage5Collector Current-Continuous1.5Collector Current-Peak3.0Collector Power Dissipation @ Tc=25°C45Junction Temperature150

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# **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{c}}\text{=}25\,^{\circ}\!\!^{\circ}\!\!^{\circ}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	250			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1.5Α; I <sub>B</sub> = 0.3Α			1.0	v
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1.5A ; V <sub>CE</sub> = 10V			1.5	V
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 150V; I <sub>B</sub> = 0			1.0	mA
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = 350V; V <sub>BE</sub> = 0			1.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1.0	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.3A ; V <sub>CE</sub> = 10V	40		250	
h <sub>FE-2</sub>	DC Current Gain	Ic= 1.5A ; Vce= 10V	10			

### h<sub>FE-1</sub> Classifications

R	Q	Р
40-90	70-150	120-250

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